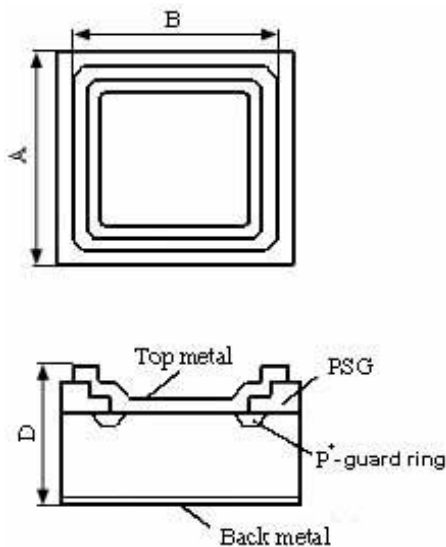


| | | 8A/60V. Die Size-80mil. | | |
|--|-------------|-------------------------|--------------------|------------------------|
| Electrical Characteristics | Symbol | Unit | Spec. limit | Die Sort |
| Breakdown Voltage @ $I_R=10mA$ | V_{BR} | V | 60 | 65 |
| Average Rectified Forward Current | $I_{F(AV)}$ | A | 8,0 | - |
| DC Forward Voltage @ 25°C, $I_F=8,0A$ | V_F | V | 0,67 | 0,65 |
| Maximum Reverse Current @ 25°C, $V_R=65V$ @ 25°C, $V_R=60V$ @ 125°C, $V_R=60V$ | I_R | mA | - 0,065 40,0 | 0,065 0,045 35,0 |
| Peak Forward Surge Current 8,3ms single half sine-wave superimposed on rated load (JEDEC METHOD) | I_{FSM} | A | 135 | - |
| Peak Repetitive Reverse Surge Current @ 2,0µs, f=1kHz., $T_J < 150^\circ C$. | I_{RRM} | A | 3,5 | |
| Electrostatic Discharge Voltage. JEDEC Method. ESD HBM. Contact. | ESD | kV | ±8 (contact) | |
| Voltage Rate of Change | dV/dt | V/µS | 10.000 | |
| Operating Junction Temperature | T_J | °C | 150 | |



| DIM | ITEM | µm |
|-------------------|---------------------|--------------|
| A_x A_y | Wafer Form Die Size | 2030 2030 |
| B_x B_y | Top Metal Size | 1890 1890 |
| D | Thickness | 350max. |
| Scribe line Width | | 80 |

Top metal:
 a) **Al** – for Wire Bonding;
 b) **Al-Ni-Ag** – for Soldering.
 Backside metal: **Ti-Ni-Ag**.